

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IRFP3206, IIRFP3206

• FEATURES

- Static drain-source on-resistance: RDs(on)≤3.0mΩ
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

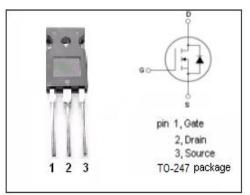
- High Efficiency Synchronous Rectification in SMPS
- Uninterruptible Power Supply
- High Speed Power Switching
- Hard Switched And High Frequency Circuits

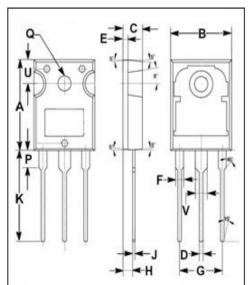
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

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SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	60	V	
V _{GS}	Gate-Source Voltage	±20	V	
ID	Drain Current-Continuous	120	А	
I _{DM}	Drain Current-Single Pulsed	840	A	
PD	Total Dissipation @T _c =25°C	280	W	
Tj	Max. Operating Junction Temperature 175		°C	
T _{stg}	Storage Temperature	-55~175	°C	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(j-c)	Channel-to-case thermal resistance	0.54	°C /W
Rth(j-a)	Channel-to-ambient thermal resistance	40	°C/W





s	mm		
DIM	MIN	MAX	
Α	19.80	20.20	
В	15.40	15.80	
С	4.90	5.10	
D	0.90	1.10	
E	1.40	1.60	
F	1.90	2.10	
G	10.80	11.00	
Н	2.40	2.60	
J	0.50	0.70	
K	19.50	20.50	
Ρ	3.90	4.10	
Q	3.30	3.50	
U	5.20	5.40	
V	2.90	3.10	



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =250 μ A	60			V
V _{GS} (th)	Gate Threshold Voltage	VDS=VGS; I _D =150 µ A	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =75A			3.0	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =60V; V _{GS} = 0V			20	μA
V _{SD}	Diode forward voltage	I _S =75A, V _{GS} = 0V			1.3	V

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